

CMOS Digital Integrated Circuits Silicon Monolithic

74HC540D,74HC541D

1. Functional Description

· Octal Bus Buffer

74HC540D: INVERTING, 3-STATE OUTPUTS 74HC541D: NON-INVERTING, 3-STATE OUTPUTS

2. General

The 74HC540D/74HC541D are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC540D is an inverting type, and the 74HC541D is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

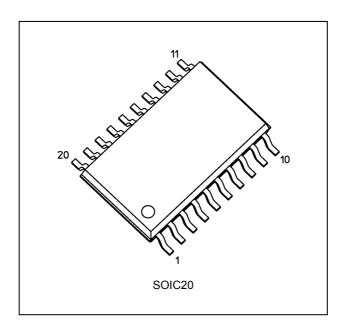
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: $t_{pd} = 10 \text{ ns (typ.)}$ at $V_{CC} = 6.0 \text{ V}$
- (3) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (4) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (5) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 6.0 V

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

4. Packaging

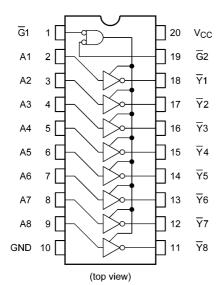


Start of commercial production

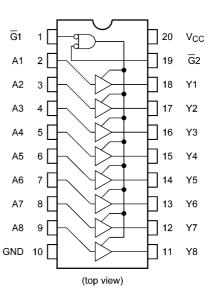


5. Pin Assignment

74HC540D

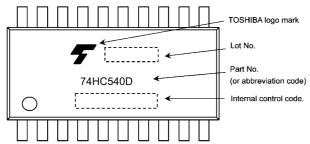


74HC541D

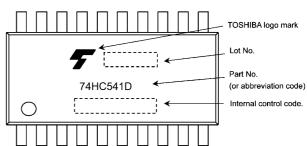


6. Marking



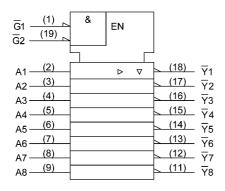




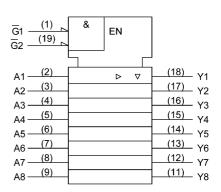


7. IEC Logic Symbol

74HC540D



74HC541D





8. Truth Table

| Input G1 | Input G2 | Input An | Output Yn | Output \overline{Y} n |
|----------|----------|----------|-----------|-------------------------|
| Н | Х | Х | Z | Z |
| Х | Н | Х | Z | Z |
| L | L | Н | Н | L |
| L | L | L | L | Н |

X: Don't care
Z: High impedance
Yn: 74HC541D
Yn: 74HC540D

9. Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 7.0 | V |
| Input voltage | V _{IN} | | -0.5 to V _{CC} + 0.5 | V |
| Output voltage | V _{OUT} | | -0.5 to V _{CC} + 0.5 | V |
| Input diode current | I _{IK} | | ±20 | mA |
| Output diode current | lok | | ±20 | mA |
| Output current | l _{out} | | ±35 | mA |
| V _{CC} /ground current | I _{CC} | | ±75 | mA |
| Power dissipation | P _D | (Note 1) | 500 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

| Characteristics | Symbol | Test Condition | Note | Rating | Unit |
|---------------------------|--------------------------------|-------------------------|----------|----------------------|------|
| Supply voltage | V _{CC} | | | 2.0 to 6.0 | V |
| Input voltage | V _{IN} | | | 0 to V _{CC} | V |
| Output voltage | V _{OUT} | | | 0 to V _{CC} | V |
| Operating temperature | T _{opr} | | (Note 1) | -40 to 125 | °C |
| Input rise and fall times | t _r ,t _f | V _{CC} = 2.0 V | | 0 to 1000 | ns |
| | | V _{CC} = 4.5 V | | 0 to 500 | |
| | | V _{CC} = 6.0 V | | 0 to 400 | |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Тур. | Max | Unit |
|--|-----------------|---|----------------------------|---------------------|------|------|------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.50 | _ | _ | V |
| | | | | 4.5 | 3.15 | _ | _ |] |
| | | | | 6.0 | 4.20 | _ | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | | _ | 0.50 | V |
| | | | | 4.5 | | _ | 1.35 | |
| | | | | 6.0 | | _ | 1.80 | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -20 μA | 2.0 | 1.9 | 2.0 | _ | V |
| | | | | 4.5 | 4.4 | 4.5 | _ | |
| | | | | 6.0 | 5.9 | 6.0 | _ | |
| | | | I_{OH} = -6 mA | 4.5 | 4.18 | 4.31 | _ | |
| | | | $I_{OH} = -7.8 \text{ mA}$ | 6.0 | 5.68 | 5.80 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 20 μA | 2.0 | | 0.0 | 0.1 | V |
| | | | | 4.5 | | 0.0 | 0.1 | |
| | | | | 6.0 | | 0.0 | 0.1 | |
| | | | I _{OL} = 6 mA | 4.5 | | 0.17 | 0.26 | |
| | | | I _{OL} = 7.8 mA | 6.0 | | 0.18 | 0.26 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 6.0 | _ | | ±0.5 | μА |
| Input leakage current | I _{IN} | $V_{IN} = V_{CC}$ or GND | | 6.0 | | _ | ±0.1 | μА |
| Quiescent supply current | I _{CC} | $V_{IN} = V_{CC}$ or GND | | 6.0 | _ | _ | 4.0 | μА |

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit |
|--|-----------------|---|----------------------------|---------------------|------|------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.50 | _ | V |
| | | | | 4.5 | 3.15 | _ | |
| | | | | 6.0 | 4.20 | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | _ | 0.50 | V |
| | | | | 4.5 | | 1.35 | |
| | | | | 6.0 | _ | 1.80 | |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH}$ or V_{IL} | I _{OH} = -20 μA | 2.0 | 1.9 | | V |
| | | | | 4.5 | 4.4 | | |
| | | | | 6.0 | 5.9 | _ | |
| | | | $I_{OH} = -6 \text{ mA}$ | 4.5 | 4.13 | _ | |
| | | | $I_{OH} = -7.8 \text{ mA}$ | 6.0 | 5.63 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 20 μA | 2.0 | _ | 0.1 | V |
| | | | | 4.5 | | 0.1 | |
| | | | | 6.0 | _ | 0.1 | |
| | | | $I_{OL} = 6 \text{ mA}$ | 4.5 | _ | 0.33 | |
| | | | $I_{OL} = 7.8 \text{ mA}$ | 6.0 | _ | 0.33 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 6.0 | _ | ±5.0 | μА |
| Input leakage current | I _{IN} | V _{IN} = V _{CC} or GND | | 6.0 | | ±1.0 | μА |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | | 6.0 | _ | 40.0 | μА |



11.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

| Characteristics | Symbol | Test Cond | ition | V _{CC} (V) | Min | Max | Unit |
|--|-----------------|---|---------------------------|---------------------|------|------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.50 | _ | V |
| | | | | 4.5 | 3.15 | _ | 1 |
| | | | | 6.0 | 4.20 | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | _ | 0.50 | V |
| | | | | 4.5 | _ | 1.35 | |
| | | | | 6.0 | _ | 1.80 | 1 |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -20 μA | 2.0 | 1.9 | _ | V |
| | | | | 4.5 | 4.4 | _ | 1 |
| | | | | 6.0 | 5.9 | _ |] |
| | | | I _{OH} = -6 mA | 4.5 | 3.7 | _ | |
| | | | I _{OH} = -7.8 mA | 6.0 | 5.2 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 20 μA | 2.0 | _ | 0.1 | V |
| | | | | 4.5 | _ | 0.1 | |
| | | | | 6.0 | _ | 0.1 | |
| | | | I _{OL} = 6 mA | 4.5 | _ | 0.4 |] |
| | | | I _{OL} = 7.8 mA | 6.0 | | 0.4 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 6.0 | _ | ±5.0 | μА |
| Input leakage current | I _{IN} | V _{IN} = V _{CC} or GND | | 6.0 | | ±1.0 | μА |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | | 6.0 | _ | 80.0 | μА |

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

| Characteristics | Part Number | Symbol | Note | Test Condition | C _L (pF) | V _{CC} (V) | Min | Тур. | Max | Unit |
|------------------------|-------------|------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|-----|------|
| Output transition time | | t _{TLH} ,t _{THL} | | | 50 | 2.0 | _ | 25 | 60 | ns |
| | | | | | | 4.5 | - | 7 | 12 | |
| | | | | | | 6.0 | | 6 | 10 | |
| Propagation delay time | | t _{PLH} ,t _{PHL} | | | 50 | 2.0 | | 36 | 90 | ns |
| | | | | | | 4.5 | - | 12 | 18 | |
| | | | | | | 6.0 | | 10 | 15 | |
| | | | | | 150 | 2.0 | | 51 | 130 | |
| | | | | | | 4.5 | | 17 | 26 | |
| | | | | | | 6.0 | 1 | 14 | 22 | |
| Output enable time | | t_{PZL},t_{PZH} | | $R_L = 1 k\Omega$ | 50 | 2.0 | 1 | 45 | 125 | ns |
| | | | | | | 4.5 | | 14 | 25 | |
| | | | | | | 6.0 | | 12 | 21 | |
| | | | | | 150 | 2.0 | 1 | 60 | 165 | |
| | | | | | | 4.5 | | 19 | 33 | |
| | | | | | | 6.0 | 1 | 16 | 28 | |
| Output disable time | | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 50 | 2.0 | - | 40 | 125 | ns |
| | | | | | | 4.5 | | 16 | 25 | |
| | | | | | | 6.0 | | 14 | 21 | |
| Input capacitance | | C _{IN} | | | | | | 5 | 10 | pF |
| Output capacitance | | C _{OUT} | | _ | | | _ | 10 | _ | pF |
| Power dissipation | 74HC540D | C _{PD} | (Note 1) | _ | | | | 32 | _ | pF |
| capacitance | 74HC541D | | | | | | _ | 35 | _ | |

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/8 \text{ (per bit)}$

11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

| Characteristics | Symbol | Test Condition | C _L (pF) | V _{CC} (V) | Min | Max | Unit |
|------------------------|------------------------------------|-------------------|---------------------|---------------------|-----|-----|------|
| Output transition time | t _{TLH} ,t _{THL} | _ | 50 | 2.0 | _ | 75 | ns |
| | | | | 4.5 | _ | 15 | |
| | | | | 6.0 | _ | 13 |] |
| Propagation delay time | t_{PLH}, t_{PHL} | _ | 50 | 2.0 | _ | 115 | ns |
| | | | | 4.5 | _ | 23 | |
| | | | | 6.0 | _ | 20 |] |
| | | | 150 | 2.0 | _ | 165 | |
| | | | | 4.5 | _ | 33 |] |
| | | | | 6.0 | _ | 28 |] |
| Output enable time | t _{PZL} ,t _{PZH} | $R_L = 1 k\Omega$ | 50 | 2.0 | _ | 155 | ns |
| | | | | 4.5 | _ | 31 | |
| | | | | 6.0 | _ | 26 |] |
| | | | 150 | 2.0 | _ | 205 | |
| | | | | 4.5 | _ | 41 |] |
| | | | | 6.0 | _ | 35 |] |
| Output disable time | t_{PLZ},t_{PHZ} | $R_L = 1 k\Omega$ | 50 | 2.0 | _ | 155 | ns |
| | | | | 4.5 | _ | 31 |] |
| | | | | 6.0 | _ | 26 | |
| Input capacitance | C _{IN} | _ | | | _ | 10 | pF |



11.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

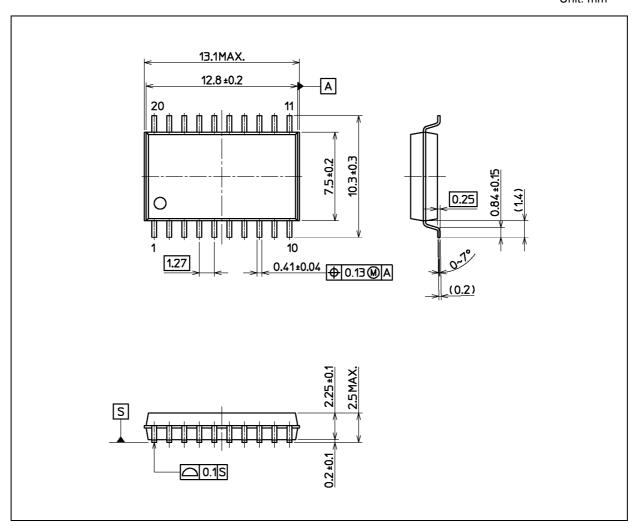
| Characteristics | Symbol | Test Condition | C _L (pF) | V _{CC} (V) | Min | Max | Unit |
|------------------------|------------------------------------|-------------------|---------------------|---------------------|-----|-----|------|
| Output transition time | t _{TLH} ,t _{THL} | _ | 50 | 2.0 | _ | 85 | ns |
| | | | | 4.5 | _ | 17 | |
| | | | | 6.0 | _ | 15 |] |
| Propagation delay time | t _{PLH} ,t _{PHL} | _ | 50 | 2.0 | _ | 135 | ns |
| | | | | 4.5 | _ | 27 | |
| | | | | 6.0 | _ | 24 |] |
| | | | 150 | 2.0 | _ | 190 | |
| | | | | 4.5 | _ | 38 | |
| | | | | 6.0 | _ | 32 |] |
| Output enable time | t_{PZL}, t_{PZH} | $R_L = 1 k\Omega$ | 50 | 2.0 | _ | 175 | ns |
| | | | | 4.5 | _ | 35 | |
| | | | | 6.0 | _ | 30 |] |
| | | | 150 | 2.0 | _ | 235 | |
| | | | | 4.5 | _ | 47 | |
| | | | | 6.0 | _ | 40 |] |
| Output disable time | t_{PLZ}, t_{PHZ} | $R_L = 1 k\Omega$ | 50 | 2.0 | _ | 175 | ns |
| | | | | 4.5 | _ | 35 |] |
| | | | | 6.0 | _ | 30 | 1 |
| Input capacitance | C _{IN} | _ | | • | _ | 10 | pF |

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

| | Package Name(s) |
|------------------|-----------------|
| Nickname: SOIC20 | |



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